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Substitute for form 1449A/PTO <b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b> (Use as many sheets as necessary)	Complete if Known	
	Application Number	Unknown
	Filing Date	Even Date Herewith
	First Named Inventor	Moradi, Behnam
	Group Art Unit	Unknown
	Examiner Name	Ramsey, Kenneth
Sheet 1 of 2	Attorney Docket No: 303.591US2	

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Examiner Initials*	Foreign Document No	Publication Date	Name of Patentee or Applicant of cited Document	Class	Subclass	T <sup>2</sup>
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Deann Zimmerman

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6/2/04

Substitute Disclosure Statement Form (PTO-1449)  
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**INFORMATION DISCLOSURE  
STATEMENT BY APPLICANT**

(Use as many sheets as necessary)

**Complete if Known**

<b>Application Number</b>	Unknown
<b>Filing Date</b>	Even Date Herewith
<b>First Named Inventor</b>	Moradi, Behnam
<b>Group Art Unit</b>	Unknown
<b>Examiner Name</b>	Ramsey, Kenneth

Sheet 2 of 2

Attorney Docket No: 303.591US2

**OTHER DOCUMENTS -- NON PATENT LITERATURE DOCUMENTS**

Examiner Initials*	Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T
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